and having an extended portion extending into the transparent region, and a first drain electrode contacting a second portion of the first active pattern.

3. The organic light emitting display device of claim **2**, wherein the capacitor comprises a lower electrode contacting the extended portion of the first source electrode, a dielectric structure disposed on the lower electrode, and an upper electrode disposed on the dielectric structure.

4. The organic light emitting display device of claim **3**, wherein the lower electrode and the first gate electrode are disposed on a same plane and formed of a same material.

5. The organic light emitting display device of claim **3**, wherein each of the lower electrode and the upper electrode includes a material having a transmittance or a material having a reflectivity.

6. The organic light emitting display device of claim **3**, wherein the dielectric structure includes a first insulating interlayer disposed on the first gate electrode and the lower electrode, and a second insulating interlayer disposed on the first insulating interlayer.

7. The organic light emitting display device of claim **3**, further comprising an insulation layer disposed on the capacitor and the at least one semiconductor device, wherein the organic light emitting structure is positioned on the insulation layer,

wherein the insulation layer includes an opening exposing the dielectric structure in the transparent region and a contact hole exposing the extended portion of the first source electrode in the pixel region.

8. The organic light emitting display device of claim **7**, wherein the upper electrode is disposed on the dielectric structure exposed by the opening, the insulation layer and a sidewall of the opening.

9. The organic light emitting display device of claim **7**, wherein the organic light emitting structure includes a first electrode contacting the exposed portion of the first source electrode through the contact hole, an organic light emitting layer disposed on the first electrode, and a second electrode disposed on the organic light emitting layer, and

wherein the upper electrode is disposed on a same plane and formed of a same material with the first electrode.

10. The organic light emitting display device of claim **7**, wherein the insulation layer has an opening exposing the exposed portion of the first source electrode and the dielectric structure.

11. The organic light emitting display device of claim **10**, wherein the upper electrode is positioned on the insulation layer, one sidewall of the opening and the dielectric structure exposed by the opening.

12. The organic light emitting display device of claim **3**, wherein the at least one semiconductor device comprises a second semiconductor device which includes a second active pattern disposed on the substrate, the first gate insulation layer disposed on the second active pattern, a second gate electrode disposed in the first gate insulation layer, a second source electrode contacting a first portion of the second active pattern, and a second drain electrode contacting a second portion of the second active pattern.

13. The organic light emitting display device of claim **12**, wherein the second gate electrode and the lower electrode are positioned respectively at different levels over the substrate.

14. The organic light emitting display device of claim **3**, further comprising an additional capacitor disposed in the pixel region.

15. The organic light emitting display device of claim **14**, wherein the additional capacitor is disposed on the first semiconductor device.

16. The organic light emitting display device of claim **15**, wherein the additional capacitor includes a lower electrode being the first gate electrode, a dielectric structure disposed on the first gate electrode, and an upper electrode disposed on the dielectric structure.

17. The organic light emitting display device of claim **16**, wherein the dielectric structure of the additional capacitor includes an insulating interlayer disposed on the first gate electrode.

18. The organic light emitting display device of claim **2**, wherein the capacitor comprises a lower electrode, a dielectric structure disposed on the lower electrode, and an upper electrode disposed on the dielectric structure and contacting the extended portion of the first source electrode.

19. The organic light emitting display device of claim **18**, wherein the upper electrode is formed of a same material with an electrode of the organic light emitting structure.

20. The organic light emitting display device of claim **19**, further comprising an additional capacitor disposed in the pixel region,

wherein the additional capacitor is disposed on the first semiconductor device,

wherein the additional capacitor includes a lower electrode being the first gate electrode, a dielectric structure disposed on the first gate electrode, and an upper electrode disposed on the dielectric structure, and

wherein the dielectric structure of the additional capacitor includes an insulating interlayer disposed on the first gate electrode.

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